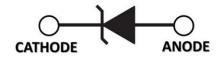
600W SURFACE MOUNT UNIDIRECTIONAL TRANSIENT VOLTAGE SUPPRESSORS DIODES 5.0V-85V

DESCRIPTION:



The ALPSMA6HSXXA series is designed to protect voltage sensitive components from high voltage, high energy transients. The SMA series is supplied in cost-effective, highly reliable package and is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.



FEATURES:

- Uni-directional
- Very low profile typical height of 1.0 mm
- 600W peak pulse power capability with a 10/1000μs waveform, repetition rate (duty cycle): 0.01%
- Low profile surface mounted application in order to optimize board space
- Excellent clamping capability
- > Low incremental surge resistance
- Glass passivated chip junction
- Lead-free parts meet RoHS requirements
- > Suffix "-H" indicates Halogen free parts, ex. ALPSMA6HSXXA-H

APPLICATIONS:

- Communication Systems
- Automotive
- Numerical and Process controls
- Medical equipment
- Business machines
- Power supplies
- Industrial/consumer applications.

MECHANICAL CHARACTERISTICS

- > Epoxy: UL94-V0 rated flame retardant.
- Case: Molded plastic, DO-221AC / SMA-HS
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Mounting Position: Any.
- Approximate Weight: 0. 037 grams.

TYPICAL DEVICE CHARACTERISTICS

MAXIMUM RATINGS @ 25°C Unless Otherwise Specified						
PARAMETER		SYMBOL	VALUE	UNITS		
Peak Power Dissipation	with a 10/1000μs waveform, Note 1, 2 & Fig. 1	P_PPM	600	W		
Peak pulse current	with a 10/1000μs waveform	I _{PPM}	See Table 1	Α		
Steady state power dissipation	at T _L =75 °C, Note 2	P _{M(AV)}	4.5	W		
Peak forward surge current	8.3ms single half sine-wave, Note 3	I _{FSM}	60	А		
Maximum instantaneours forward voltage	at I _F =25 For uni-directional types only, Note 4	V_{F}	3.5	V		
Typical thermal resistance	Junction to case Junction to ambient	R _{θJC} R _{θJA}	32 52	°C/W		
Operating junction temperature range		TJ	−55 to +150	°C		
Storage Temperature Range		T_{STG}	−65 to +175	°C		

NOTE

- 1. Non-repetitive current pulse, per Fig. 3 and derated above T_A =25°C per Fig. 2
- 2. Mounted on copper pad area of 0.2"x0.2" (5.0x5.0 mm) per Fig 5
- 3. Measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle=4 pulses per minute maximum
- 4. $V_F < 3.5V$ for $V_{BR} < 200V$.

ELECTRICAL CHARACTERISTICS PER LINE @ 25°C Unless Otherwise Specified							
PART NUMBER (UNI)	REVERSE STAND-OFF VOLTAGE V	BREAKDOWN VOLTAGE V (BR) @ I T VOLTS		TEST CURRENT @ I _T	MAXIMUM CLAMPING VOLTAGE @ I _{PP} V _C		MAXIMUM REVERSE LEAKAGE CURRENT @V _{RWM} Ι _R μΑ
	VOLTS	MIN	MAX	mA	VOLTS		
ALPSMA6HS5.0A	5.0	6.40	7.00	10	9.2	65.2	800
ALPSMA6HS6.0A	6.0	6.67	7.37	10	10.3	58.3	800
ALPSMA6HS6.5A	6.5	7.22	7.98	10	11.2	53.6	500
ALPSMA6HS7.0A	7.0	7.78	8.60	10	12.0	50.0	200
ALPSMA6HS7.5A	7.5	8.33	9.21	1.0	12.9	46.5	100
ALPSMA6HS8.0A	8.0	8.89	9.83	1.0	13.6	44.1	50
ALPSMA6HS8.5A	8.5	9.44	10.4	1.0	14.4	41.7	20
ALPSMA6HS9.0A	9.0	10.0	11.1	1.0	15.4	39.0	10
ALPSMA6HS10A	10	11.1	12.3	1.0	17.0	35.3	5
ALPSMA6HS11A	11	12.2	13.5	1.0	18.2	33.0	5
ALPSMA6HS12A	12	13.3	14.7	1.0	19.9	30.2	5
ALPSMA6HS13A	13	14.4	15.9	1.0	21.5	27.9	5
ALPSMA6HS14A	14	15.6	17.2	1.0	23.2	25.9	5
ALPSMA6HS15A	15	16.7	18.5	1.0	24.4	24.6	5



beyond boundaries...

ALPSMA6HSXXA Series SMA-HS

ELECTRICAL CHARACTERISTICS PER LINE @ 25°C Unless Otherwise Specified							
PART NUMBER (Notes 1-2)	REVERSE STAND-OFF VOLTAGE V _{RWM} VOLTS	BREAKDOWN VOLTAGE V (BR) @ I T VOLTS		TEST CURRENT	MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ I _p V _c VOLTS	MAXIMUM REVERSE SURGE CURRENT @Ipp AMPS	MAXIMUM REVERSE LEAKAGE CURRENT @V _{RWM} I _R μΑ
		MIN	MAX	mA	VOLIS		
ALPSMA6HS16A	16	17.8	19.7	1.0	26.0	23.0	5
ALPSMA6HS17A	17	18.9	20.9	1.0	27.6	21.7	5
ALPSMA6HS18A	18	20.0	22.1	1.0	29.2	20.5	5
ALPSMA6HS20A	20	22.2	24.5	1.0	32.4	18.5	5
ALPSMA6HS22A	22	24.4	26.9	1.0	35.5	16.9	5
ALPSMA6HS24A	24	26.7	29.5	1.0	38.9	15.4	5
ALPSMA6HS26A	26	28.9	31.9	1.0	42.1	14.2	5
ALPSMA6HS28A	28	31.1	34.4	1.0	45.4	13.2	5
ALPSMA6HS30A	30	33.3	36.8	1.0	48.4	12.4	5
ALPSMA6HS33A	33	36.7	40.6	1.0	53.3	11.2	5
ALPSMA6HS36A	36	40.0	44.2	1.0	58.1	10.3	5
ALPSMA6HS40A	40	44.4	49.1	1.0	64.5	9.3	5
ALPSMA6HS43A	43	47.8	52.8	1.0	69.4	8.6	5
ALPSMA6HS45A	45	50.0	55.3	1.0	72.7	8.2	5
ALPSMA6HS48A	48	53.3	58.9	1.0	77.4	7.7	5
ALPSMA6HS51A	51	56.7	62.7	1.0	82.4	7.2	5
ALPSMA6HS54A	54	60.0	66.3	1.0	87.1	6.9	5
ALPSMA6HS58A	58	64.4	71.2	1.0	93.6	6.4	5
ALPSMA6HS60A	60	66.7	73.7	1.0	96.8	6.2	5
ALPSMA6HS64A	64	71.1	78.6	1.0	103.0	5.8	5
ALPSMA6HS70A	70	77.8	86.0	1.0	113.0	5.3	5
ALPSMA6HS75A	75	83.3	92.1	1.0	121.0	4.9	5
ALPSMA6HS78A	78	86.7	95.8	1.0	126.0	4.7	5
ALPSMA6HS85A	85	94.4	104	1.0	137.0	4.3	5

NOTE

- 1. V_{BR} measured after I_T applied for 300 μ s, I_T = square wave pulse or equivalent
- 2. Surge current waveform per Fig. 3 and derated per Fig. 2
- 3. Suffix 'A' denotes 5% tolerance devices
- 4. All terms and symbols are consistent with ANS/IEEE C62.35
- 5. Transient Voltage Suppressors (TVS) are devices used to protect vulnerable circuits from electrical overstress such as that caused by electrostatic discharge, inductive load switching and induced lightning. Within the TVS, damaging voltage spikes are limited by clamping or avalanche action of a rugged silicon pn junction which reduces the amplitude of the transient to a nondestructive level. See Fig. 7 & Fig. 8

TYPICAL DEVICE CHARACTERISTICS CURVES

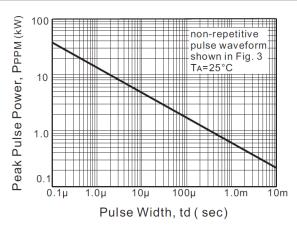


Fig1. PEAK PULSE POWER RATING CURVE

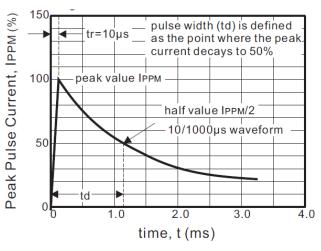


Fig3. PULSE WAVEFORM

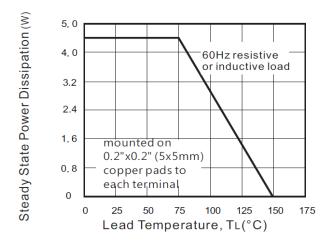


Fig.5 STEADY STATE POWER DERATING CURVE

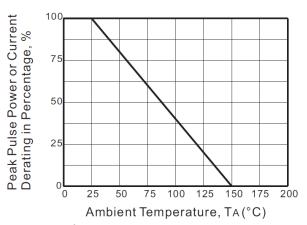


Fig2. PULSE DERATING CURVE

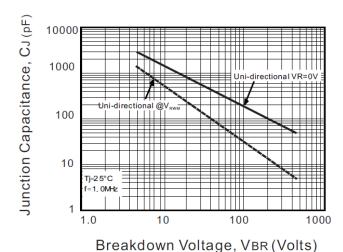


Fig4. TYPICAL JUNCTION CAPACITANCE

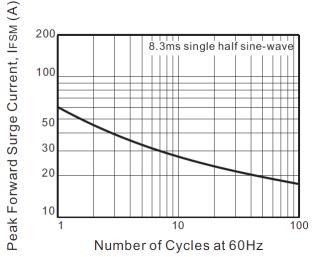


Fig. 6 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

RATING AND CHARACTERISTICS CURVES

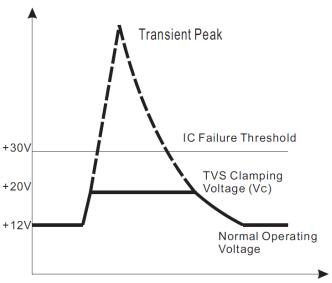


Fig. 7 - TRANSIENTS OF SEVERAL THOUSAND VOLTS CAN BE CLAMPED TO A SAFE LEVEL BY THE TVS

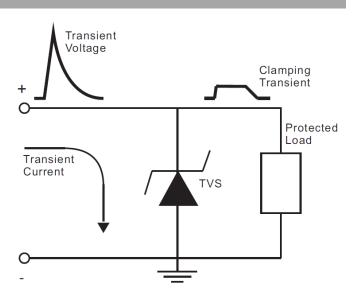


Fig. 8 - TRANSIENT CURRENT IS DIVERTED TO GROUND THRU
TVS; THE VOLTAGE SEEN BY THE PROTECTED LOAD
IS LIMITED TO THE CLAMPING VOLTAGE LEVEL



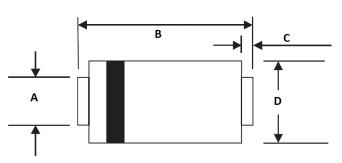
PINNING INFORMATION

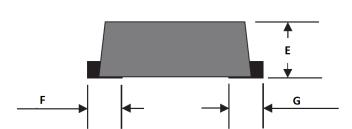
PIN	SIMPLIFIED OUTLINE	SYMBOL
Uni-Directional Pin1 cathode Pin2 anode	1 2	12



PACKAGE INFORMATION

DO-221AC / SMA-HS

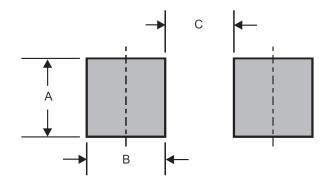




OUTLINE DIMENSIONS						
DIM	MILLIMET	TERS	INCHES			
Dilli	MIN MAX		MIN	MAX		
Α	1.15	1.75	0.045	0.069		
В	5.00	5.40	0.197	0.213		
С	0.4	45 Typ.	0.018 Тур.			
D	2.40	2.80	0.095	0.111		
E	0.95	1.05	0.037	0.041		
F	1.0 Typ.		0.040	Тур.		
G	1.0 Тур.		0.040	Тур.		

NOTES

1. Dimensions are exclusive of mold flash and metal burrs.



	PAD LAYOUT DIMENSIONS						
DIM	MILLIME	TERS	INCHES				
Dilvi	MIN	MAX	MIN	MAX			
А	1.52	-	0.060	-			
В	1.20	-	0.048	-			
С	3.12	-	0.123	-			

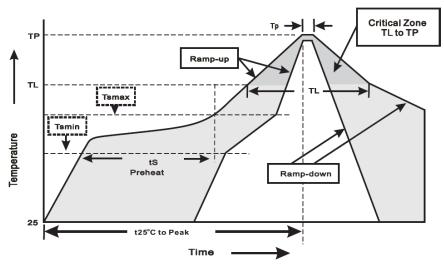
SOLDERING PARAMETERS

SUGGESTED THERMAL PROFILES FOR SOLDERING PROCESSES

1. Storage environment: Temperature=5 °C~40 °C Humidity=55% ±25%

beyond boundaries...

2. Reflow soldering of surface-mount devices



3. Reflow soldering

PROFILE FEATURE	SOLDERING CONDITION
Average ramp-up rate (T _L to T _P)	<3 °C/sec
Preheat	
- Temperature Min (T _{smin})	150 °C
- Temperature Max (T _{smax})	200 °C
- Time (min to max) (t _s)	60 ~ 120 sec
T _{smax} to T _L	
- Ramp-upRate	<3 °C/sec
Time maintained above:	
- Temperature (T _L)	217 °C
- Time(tL)	60 ~ 260 sec
Peak Temperature (T _P)	255 °C-0/+5 °C
Time within 5 °C of actual Peak	10 ~ 30 sec
Temperature(tP)	
Ramp-down Rate	<6 °C/sec
Time 25 °C to Peak Temperature	<6 minutes



PRODUCT HIGH RELIABLITY TEST CAPABILITIES

ITEM	TEST CONDITIONS	STANDARD
Solder Resistance	At 260±5°C for 10±Sec.	MIL-STD-750D
		METHOD-2031
Solderability	At 245±5°C for 5 sec.	MIL-STD-202F
		METHOD-208
High Temperature Reverse Bias	V _{BR} = V _{BR} N _{OM} *80% at T _J =150° for 168 hrs.	MIL-STD-750D
		METHOD-1038
Pressure Cooker	15P _{SIG} at T _A =121°C for 4Hrs	JESD22-A102
Temperature Cycling	-55°C to +125°C dwelled for 30min and	MIL-STD-750D
	transferred for 5min. total 10 cycles.	METHOD-1051
Humidity	At T _A =85°C, RH=85% for 1000hrs.	MIL-STD-750D
·		METHOD-1021
High Temperature Storage Life	At 175°C for 1000hrs.	MIL-STD-750D
		METHOD-1031

CUSTOMER NOTE:

DISCLAIMER

The product information and the selection guide facilitates the selection of the ALPINESEMI™'s Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review the Data sheet(s) so as to confirm that the Device(s) meets functionality parameters for your application. The information furnished on the Data Sheet and the ALPINESEMI™'s Web Site is believed to be accurate and reliable at the time of preparation of this document. ALPINESEMI™ however, does not assume any inaccuracies that may arise when the components are mounted and removed. Furthermore, ALPINESEMI™ does not assume liability whatsoever, arising out of the application or the use of any of ALPINESEMI™'s product(s). Neither, does it convey any license under its patent rights nor the rights of others. These products are not guaranteed for use in life saving/support appliances or systems. ALPINESEMI™'s customers using these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and ALPINESEMI™ will not be responsible in any way(s) for any damage(s) resulting from such use.

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Component Disposal Instructions

- 1. ALPINESEMI™ Semiconductor Devices are RoHS compliant and hence customers are requested to dispose as per the prevailing Environmental Legislation put forth in their specific country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).



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